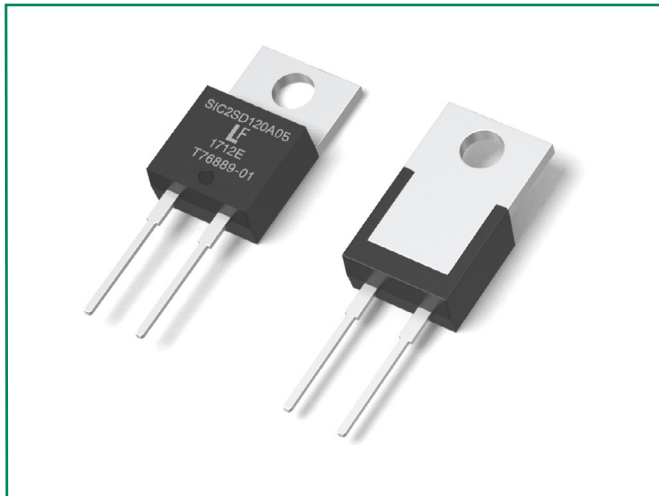


### LSIC2SD120A05



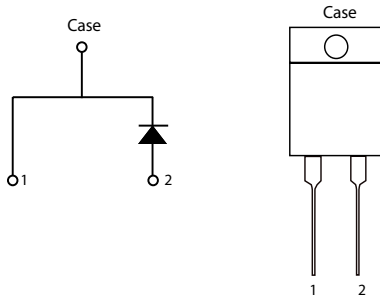
#### Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

#### Circuit Diagram TO-220-2L



#### Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

#### Environmental

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = PB-free lead plating

#### Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1200	V
DC Blocking Voltage	$V_R$	$T_j = 25\text{ °C}$	1200	V
Continuous Forward Current	$I_F$	$T_c = 25\text{ °C}$	17.5	A
		$T_c = 135\text{ °C}$	8.5	
		$T_c = 158\text{ °C}$	5	
Non-Repetitive Forward Surge Current	$I_{FSM}$	$T_c = 25\text{ °C}, T_p = 10\text{ ms}, \text{Half sine pulse}$	40	A
Power Dissipation	$P_{Tot}$	$T_c = 25\text{ °C}$	100	W
		$T_c = 110\text{ °C}$	43.3	
Operating Junction Temperature	$T_j$	-	-55 to 175	°C
Storage Temperature	$T_{STG}$	-	-55 to 150	°C
Soldering Temperature (reflow MSL 1)	$T_{sold}$	-	260	°C

**Electrical Characteristics**

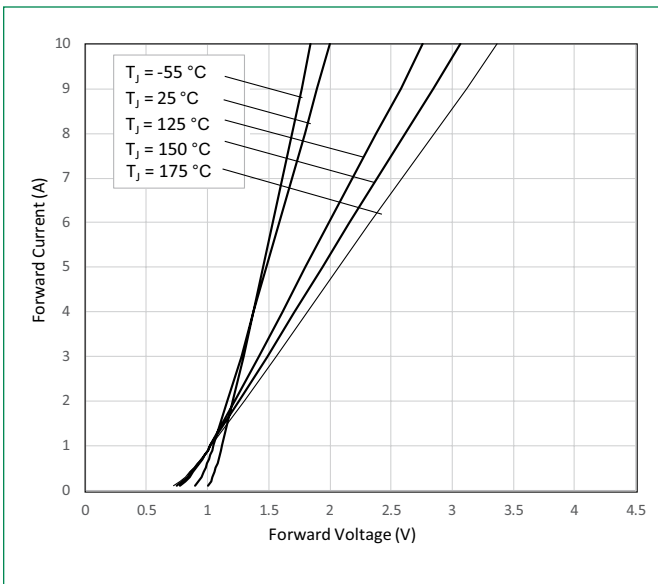
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F = 5 \text{ A}, T_J = 25 \text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 5 \text{ A}, T_J = 175 \text{ }^\circ\text{C}$	-	2.1		
Reverse Current	$I_R$	$V_R = 1200 \text{ V}, T_J = 25 \text{ }^\circ\text{C}$	-	<1	100	$\mu\text{A}$
		$V_R = 1200 \text{ V}, T_J = 175 \text{ }^\circ\text{C}$	-	5		
Total Capacitance	C	$V_R = 1 \text{ V}, f = 1 \text{ MHz}$	-	310		pF
		$V_R = 400 \text{ V}, f = 1 \text{ MHz}$	-	29		
		$V_R = 800 \text{ V}, f = 1 \text{ MHz}$	-	21		
Total Capacitive Charge	$Q_C$	$V_R = 800 \text{ V}, Q_C = \int_0^{V_R} C(V) dV$	-	30		nC

Footnote:  $T_J = +25 \text{ }^\circ\text{C}$  unless otherwise specified

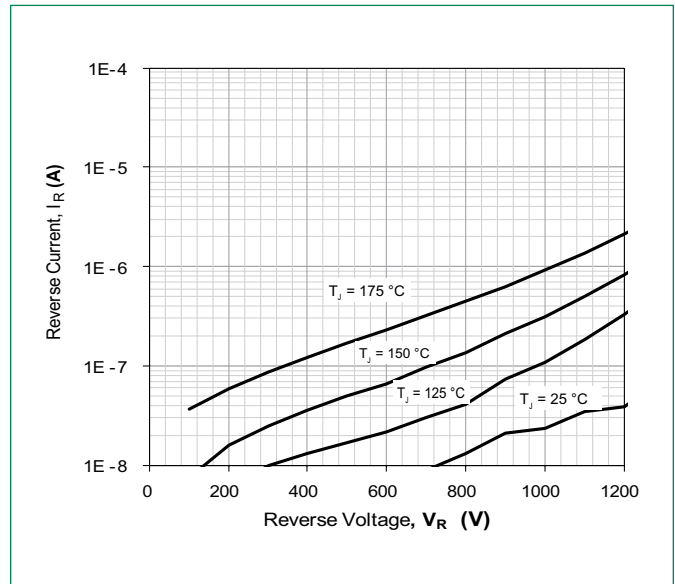
**Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance	$R_{\theta JC}$	-	-	1.50		$^\circ\text{C/W}$

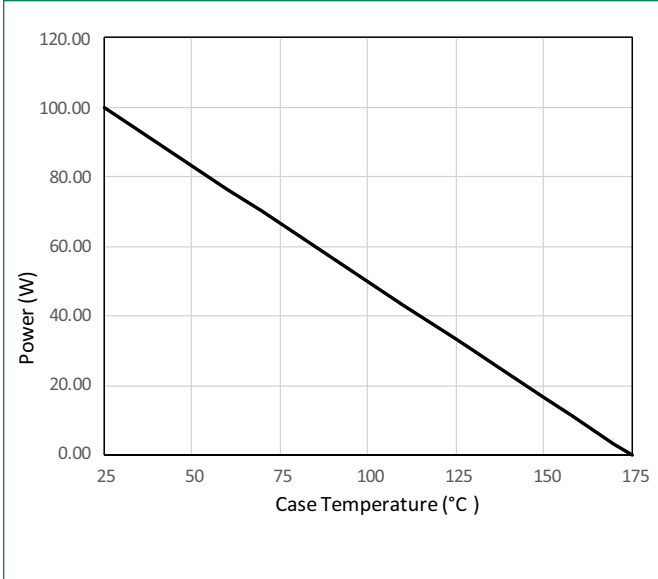
**Figure 1: Typical Forward Characteristics**



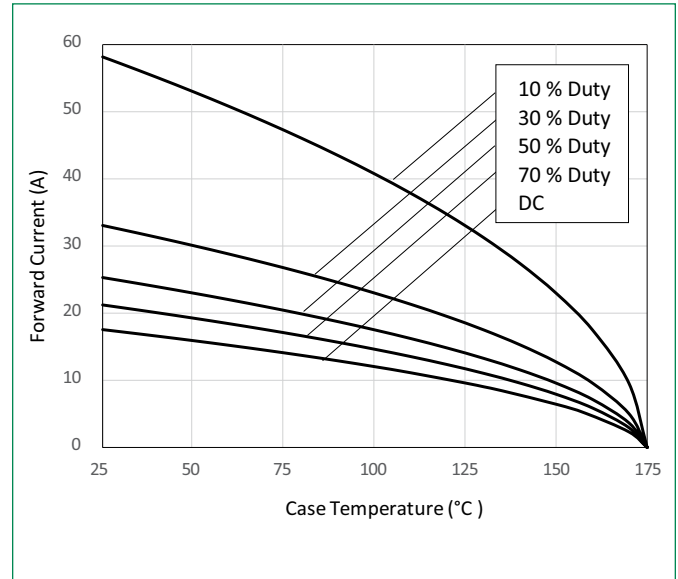
**Figure 2: Typical Reverse Characteristics**



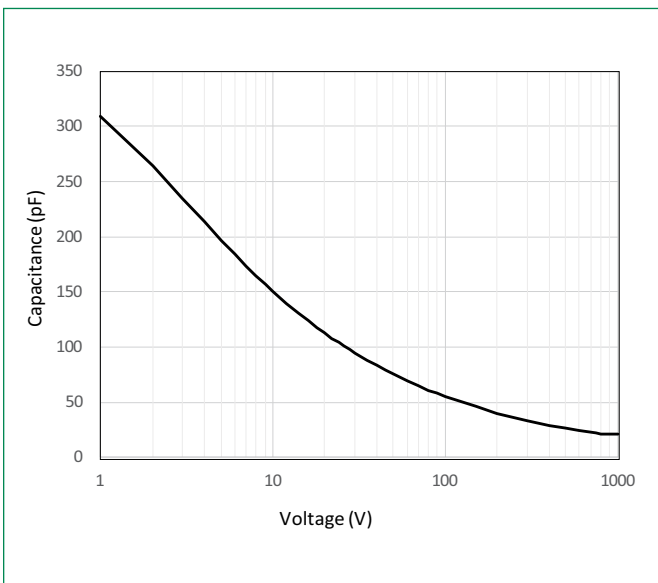
**Figure 3: Power Derating**



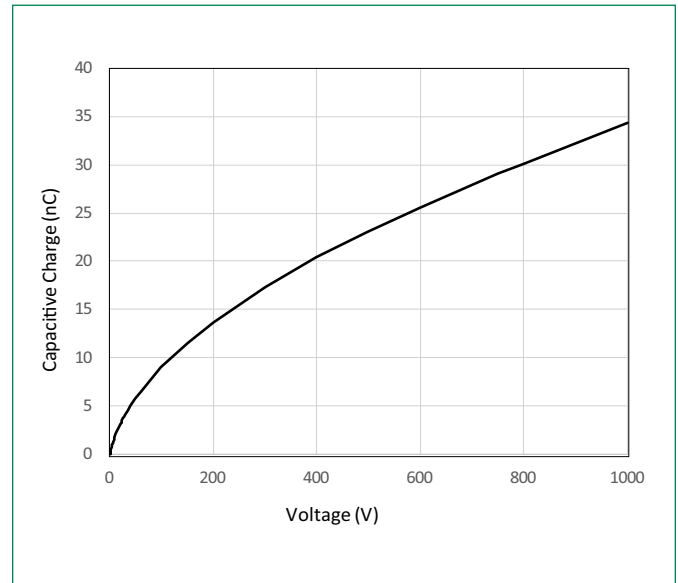
**Figure 4: Current Derating**



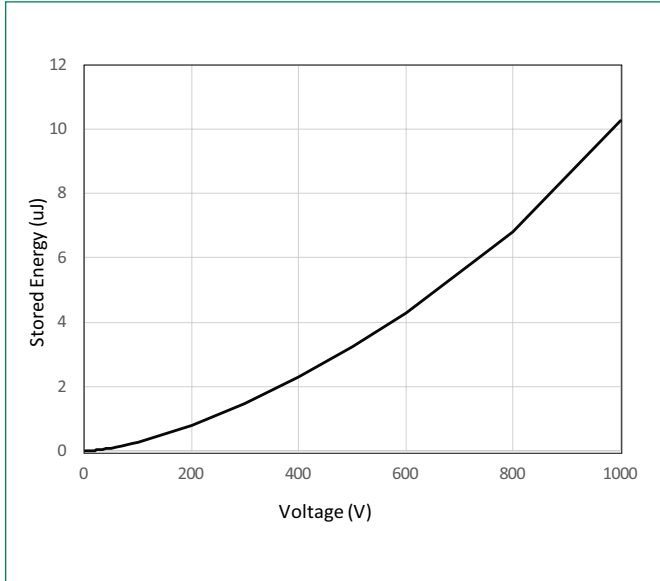
**Figure 5: Capacitance vs. Reverse Voltage**



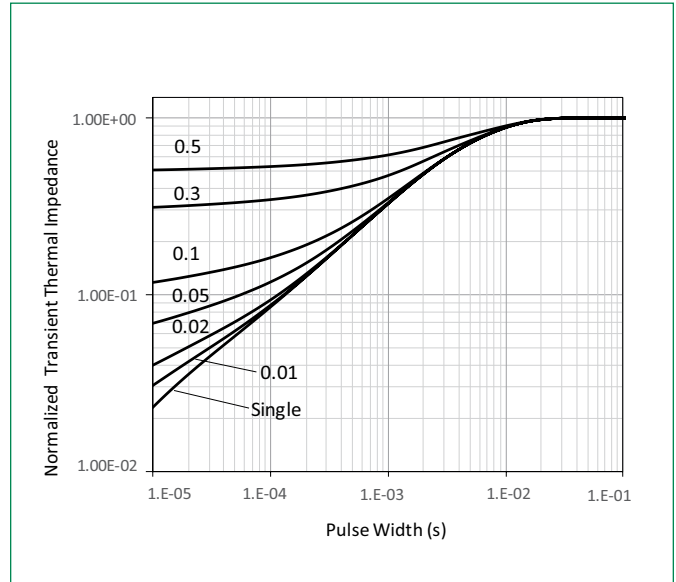
**Figure 6: Capacitive Charge vs. Reverse Voltage**



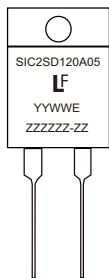
**Figure 7: Stored Energy vs. Reverse Voltage**



**Figure 8: Transient Thermal Impedance**



**Part Numbering and Marking System**

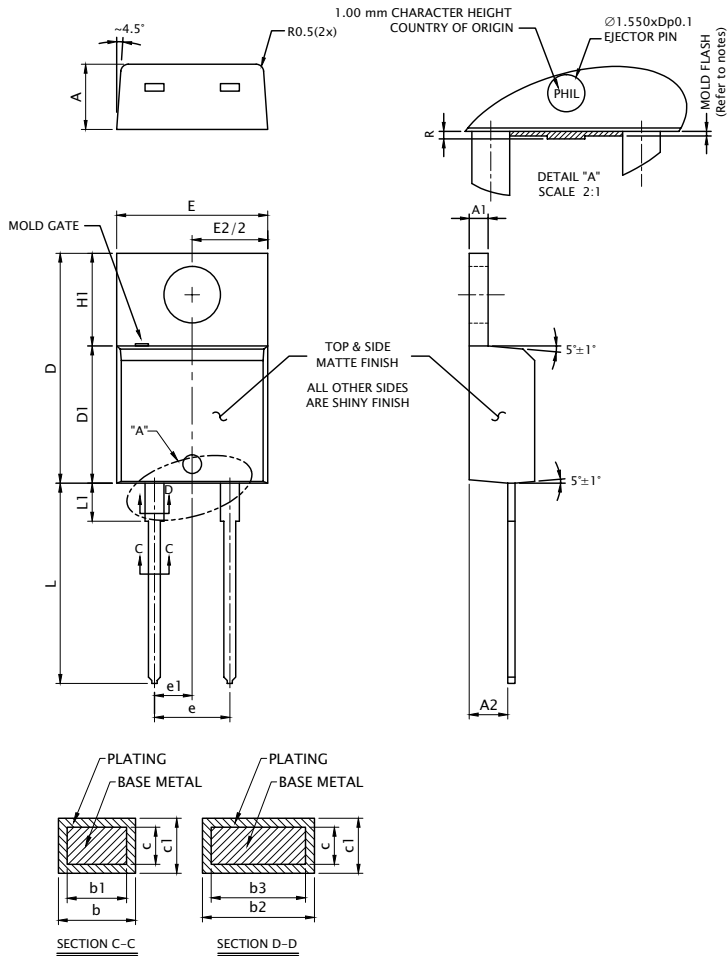


- SIC = SiC Diode
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- A = TO-220-2L
- 05 = Current Rating (5 A)
- YY = Year
- WW = Week
- E = Special Code
- ZZZZZ-ZZ = Lot Number

**Packing Options**

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A05	SIC2SD120A05	Tube	1000

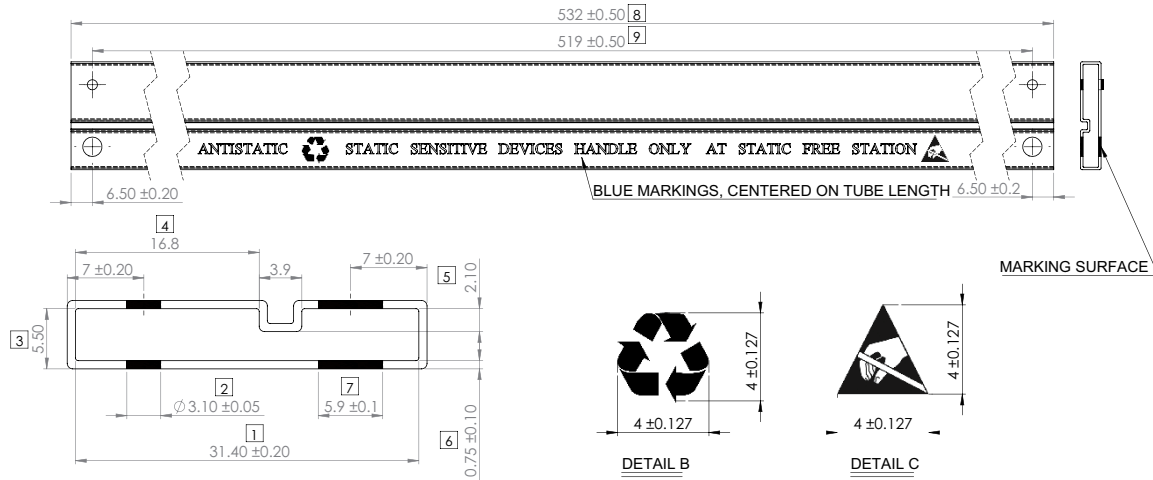
### Dimensions-Package TO-220-2L



Symbol	Millimeters		
	Min	Nominal	Max
A	4.320	4.450	4.570
A1	1.140	1.270	1.400
A2	2.500	-	2.740
b	0.690	-	0.880
b1	0.680	-	0.870
b2	1.230	-	1.390
b3	1.220	1.270	1.380
c	0.360	-	0.503
c1	0.630	-	0.527
D	14.900	-	15.600
D1	8.615	-	9.017
D2	12.840	-	12.950
E	10.000	10.180	10.360
E1	7.570	7.610	7.680
e1	2.490	2.540	2.590
e	5.030	5.080	5.130
H1	6.295	6.545	6.795
L	13.000	13.500	14.00
L1	2.390	-	3.250
øP	3.710	3.840	3.960
Q	2.650	-	3.050
R	-	-	0.254

- NOTES:
1. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 MM PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREME OF PLASTIC BODY.
  2. DIMENSIONS E2 & H1 DEFINE A ZONE WHERE STAMPING AND SINGULATION IRREGULARITIES RE ALLOWED.

### Packing Specification (Tube for TO-220-2L )



**NOTES:**

1. Material transparent extruded PVC with antistatic dipping
2. Radius : 0.5 maximum unless otherwise specified
3. Critical areas : Labelled in Box
4. All pin plug holes are considered critical dimension
5. Marking Font Type : Times new roman, 3.12 ± 0.127 in height
6. Material Thickness : 0.75 ± 0.10
7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°
8. Unit : Millimeter (mm)

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